NSN 5961-01-003-2623

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-003-2623
Inclosure Material:
Metal
Overall Length:
0.565 inches
Overall Height:
0.565 inches
Overall Width:
0.683 inches
Mounting Facility Quantity:
1
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Thread Size:
0.224 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
1000.0 repetitive peak off-state voltage
Current Rating Per Characteristic:
80.00 amperes drain current torr
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0